NSN 5961-00-231-3830

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-231-3830 **Inclosure Material:** Metal **Overall Length:** Between 0.150 inches and 0.180 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-78 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 0.60 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: pnp **Test Data Document:** 80063-sm-b-650897 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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